

Product data sheet

Product profile 1.

1.1 General description

Hyperfast power diode in a SOD59 (2-lead TO-220AC) plastic package.

1.2 Features and benefits

- Low reverse recovery current and low thermal resistance
- Reduces switching losses in associated MOSFET

1.3 Applications

- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- Half-bridge/full-bridge switched-mode power supplies
- Half-bridge lighting ballasts

1.4 Quick reference data

Table 1. Quick reference data

Parameter	Conditions	Min	Тур	Max	Unit
repetitive peak reverse voltage		-	-	500	V
average forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \le 129 \text{°C}$; see Figure 1; see Figure 2	-	-	5	Α
racteristics					
forward voltage	$I_F = 5 \text{ A}; T_j = 25 \text{ C};$ see Figure 5	-	1.5	2	V
	$I_F = 5 \text{ A}; T_j = 150 \text{ C};$ see Figure 5	-	1.15	1.45	V
haracteristics					
reverse recovery time	$I_F = 5 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 500 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ C}$; see Figure 6	-	16	-	ns
	repetitive peak reverse voltage average forward current racteristics forward voltage haracteristics	repetitive peak reverse voltage $ \begin{array}{ll} \text{average forward} & \text{square-wave pulse; } \delta = 0.5 \ ; \\ T_{mb} \leq 129 \ \mathbb{C}; \ \text{see } \underline{ \text{Figure 1}}; \\ \text{see } \underline{ \text{Figure 2}} \\ \\ \text{forward voltage} & I_F = 5 \ \text{A; } T_j = 25 \ \mathbb{C}; \\ \text{see } \underline{ \text{Figure 5}} \\ \hline I_F = 5 \ \text{A; } T_j = 150 \ \mathbb{C}; \\ \text{see } \underline{ \text{Figure 5}} \\ \\ \text{haracteristics} \\ \\ \text{reverse recovery time} & I_F = 5 \ \text{A; } V_R = 400 \ \text{V;} \\ \text{d}_{I_F}/\text{d}t = 500 \ \text{A/}\mu\text{s; } T_j = 25 \ \mathbb{C}; \\ \end{array} $	repetitive peak reverse voltage $ \begin{array}{ccccccccccccccccccccccccccccccccccc$	repetitive peak reverse voltage $ \begin{array}{ccccccccccccccccccccccccccccccccccc$	repetitive peak reverse voltage $ \begin{array}{ccccccccccccccccccccccccccccccccccc$



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	Α	anode	mb	K
mb	mb	mounting base; connected to cathode		
			SOD59 (TO-220AC)	

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BYC5D-500	TO-220AC	plastic single-ended package; heatsink mounted; 1 mounting hole; 2-lead TO-220AC	SOD59

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	500	V
V_{RWM}	crest working reverse voltage		-	500	V
V_R	reverse voltage	DC	-	500	V
I _{F(AV)}	average forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \le 129 ^{\circ}C$; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	5	Α
I _{FRM}	repetitive peak forward current	square-wave pulse; $\delta = 0.5$; $t_p = 25 \mu s$; $T_{mb} \le 129 \degree C$	-	10	Α
I _{FSM}	non-repetitive peak forward current	t_p = 8.3 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see Figure 3	-	44	Α
		t_p = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C; see <u>Figure 3</u>	-	40	A
T _{stg}	storage temperature		-40	150	$\mathcal C$
Tj	junction temperature		-	150	C

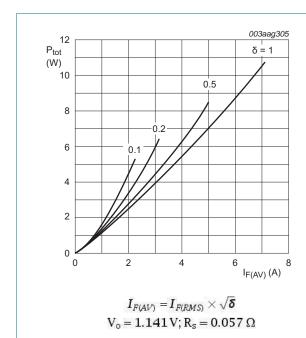


Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

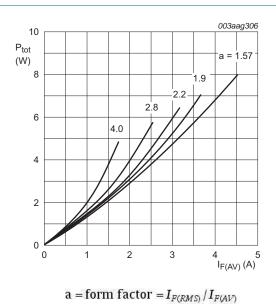
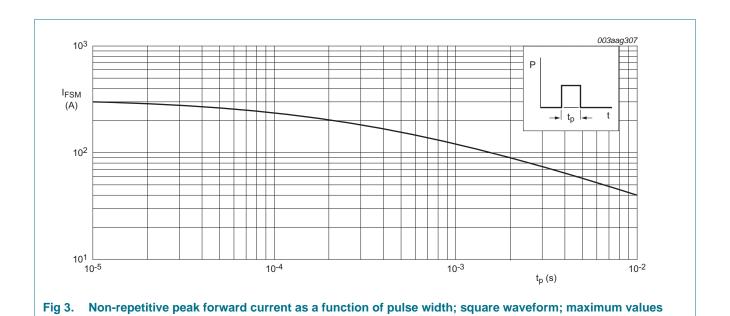


Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

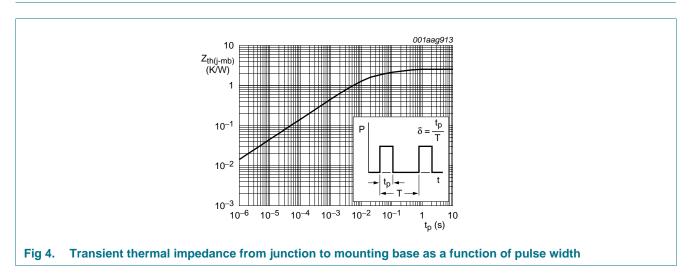
 $V_o = 1.141 \, V; R_s = 0.057 \, \Omega$



5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see <u>Figure 4</u>	-	-	2.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _F forward volta	forward voltage	$I_F = 10 \text{ A}; T_j = 150 \text{C}; \text{ see } \frac{\text{Figure 5}}{}$	-	1.4	1.7	V
		$I_F = 5 \text{ A}; T_j = 25 \text{ C}; \text{ see } \frac{\text{Figure 5}}{}$	-	1.5	2	V
		$I_F = 5 \text{ A}$; $T_j = 150 \text{C}$; see Figure 5	-	1.15	1.45	V
R reverse current	V _R = 500 V	-	9	40	μΑ	
		$V_R = 500 \text{ V}; T_j = 100 ^{\circ}\text{C}$	-	0.9	3	mA
Dynamic ch	naracteristics					
t _{rr} reverse recove	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 50 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ C}$; see Figure 6	-	15	30	ns
		$I_F = 5 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 500 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ C}$; see Figure 6	-	16	-	ns
I _{RM}	peak reverse recovery current	$I_F = 5 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 50 \text{ A/}\mu\text{s}$; $T_j = 125 \text{ C}$; see Figure 6	-	0.9	3	Α
		$I_F = 5 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 500 \text{ A/}\mu\text{s}$; $T_j = 100 \text{ C}$; see Figure 6	-	9.5	11	Α
V_{FR}	forward recovery voltage	$I_F = 5 \text{ A}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ C}$; see Figure 7	-	9	11	V

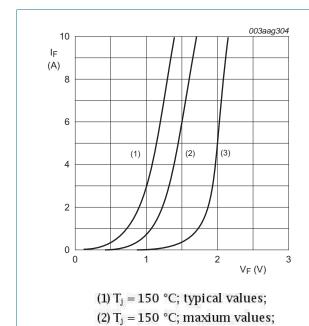


Fig 5. Forward current as a function of forward voltage

(3) T_j = 25 °C; maxium values; V_o = 1.141 V; R_s = 0.057 Ω

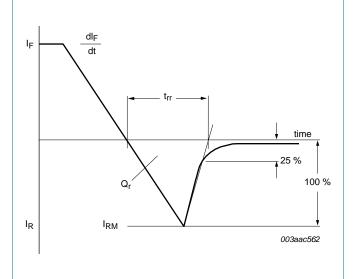
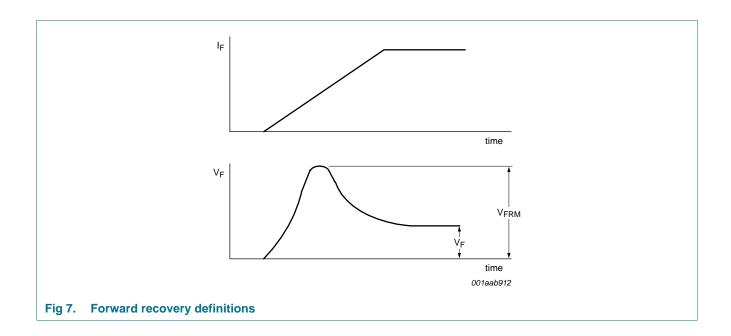


Fig 6. Reverse recovery definitions; ramp recovery



7. Package outline

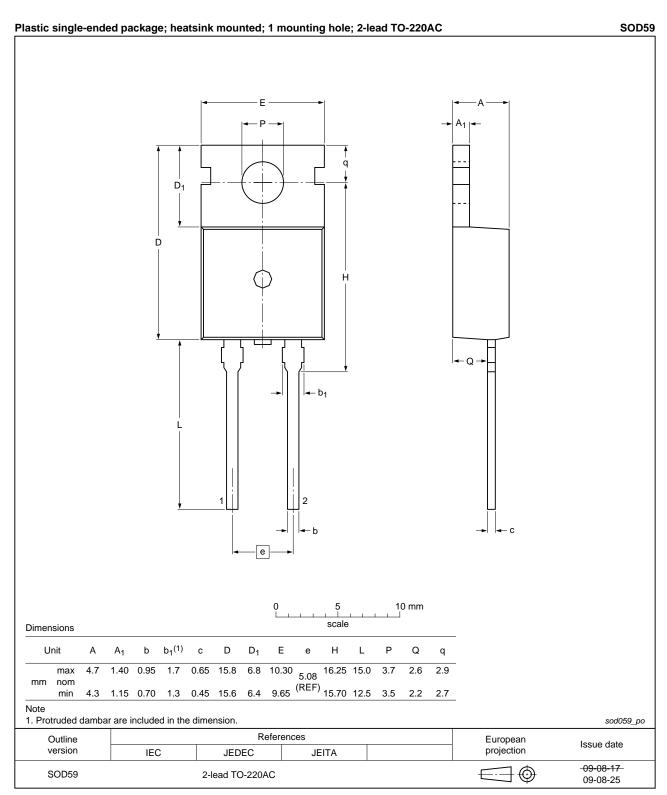


Fig 8. Package outline SOD59 (TO-220AC)



8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYC5D-500 v.1	20110706	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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